

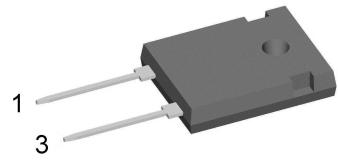
FRED

V_{RRM} = 600 V
 I_{FAV} = 25 A
 t_{rr} = 35 ns

Single Diode

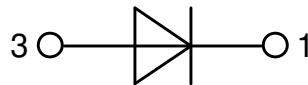
Part number

DFE25I600HA



Backside: Isolated

 E72873



Features / Advantages:

- Planar passivated chips
- Low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

Disclaimer Notice

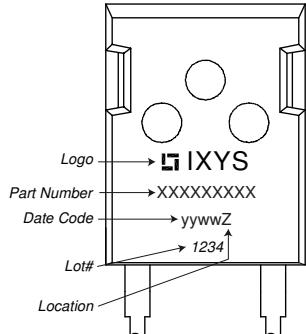
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Fast Diode

| Symbol | Definition | Conditions | Ratings | | | |
|-------------------|--|--|---|-----------|------------------------------|-----------------------|
| | | | min. | typ. | max. | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^\circ\text{C}$ | | | 600 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^\circ\text{C}$ | | | 600 | V |
| I_R | reverse current, drain current | $V_R = 600 \text{ V}$ $V_R = 480 \text{ V}$ | $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$ | | 100 6 | μA mA |
| V_F | forward voltage drop | $I_F = 25 \text{ A}$ $I_F = 50 \text{ A}$ $I_F = 25 \text{ A}$ $I_F = 50 \text{ A}$ | $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$ | | 1.30 1.52 1.03 1.31 | V V |
| I_{FAV} | average forward current | $T_C = 110^\circ\text{C}$ rectangular $d = 0.5$ | $T_{VJ} = 150^\circ\text{C}$ | | 25 | A |
| V_{F0} r_F | threshold voltage slope resistance } for power loss calculation only | | $T_{VJ} = 150^\circ\text{C}$ | | 0.78 10.2 | V $\text{m}\Omega$ |
| R_{thJC} | thermal resistance junction to case | | | | 1.2 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | 0.25 | | K/W |
| P_{tot} | total power dissipation | | $T_C = 25^\circ\text{C}$ | | 105 | W |
| I_{FSM} | max. forward surge current | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$ | $T_{VJ} = 45^\circ\text{C}$ | | 240 | A |
| C_J | junction capacitance | $V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$ | $T_{VJ} = 25^\circ\text{C}$ | 20 | | pF |
| I_{RM} | max. reverse recovery current | | $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$ | 9 14 | | A |
| t_{rr} | reverse recovery time | $I_F = 30 \text{ A}; V_R = 300 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$ | $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$ | 50 120 | | ns ns |

Package TO-247

| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
|---------------|-------------------------------------|--------------|------|------|------|------|
| I_{RMS} | <i>RMS current</i> | per terminal | | | 50 | A |
| T_{VJ} | <i>virtual junction temperature</i> | | -55 | | 150 | °C |
| T_{op} | <i>operation temperature</i> | | -55 | | 125 | °C |
| T_{stg} | <i>storage temperature</i> | | -55 | | 150 | °C |
| Weight | | | | 6 | | g |
| M_d | <i>mounting torque</i> | | 0.8 | | 1.2 | Nm |
| F_c | <i>mounting force with clip</i> | | 20 | | 120 | N |

Product Marking

Part description

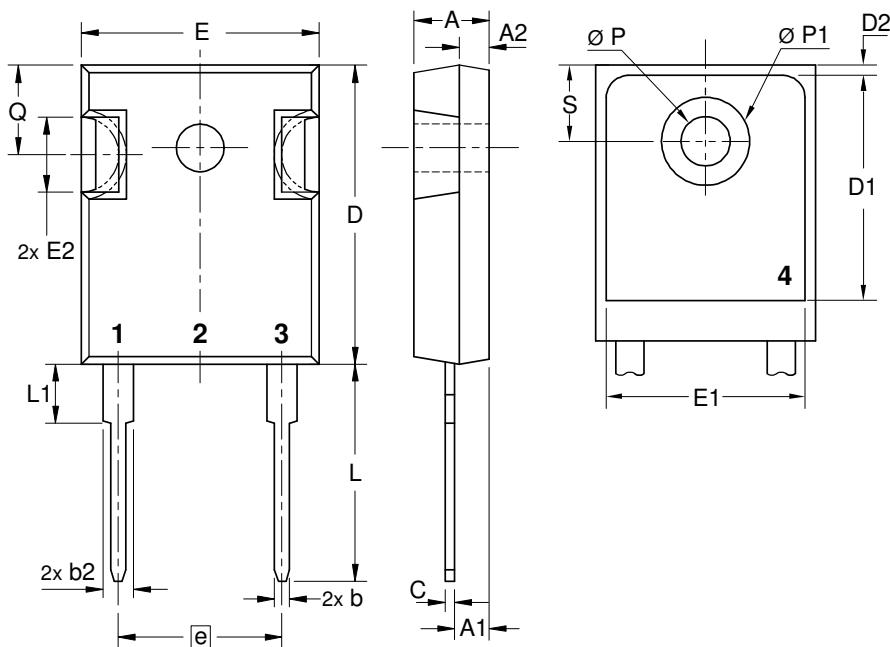
D = Diode
F = FRED
E = fast, low VF
25 = Current Rating [A]
I = Single Diode
600 = Reverse Voltage [V]
HA = TO-247AD (2)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DFE25I600HA | DFE25I600HA | Tube | 30 | 521189 |

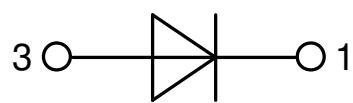
| Similar Part | Package | Voltage class |
|--------------|----------------------|---------------|
| DSEI25-06A | TO-220AC (2) | 600 |
| DSEI25-06AS | TO-263AB (D2Pak) (2) | 600 |

Equivalent Circuits for Simulation
* on die level
 $T_{VJ} = 150^\circ\text{C}$

| | | |
|--------------|--------------------|--------|
| | Fast Diode | |
| $V_{0\ max}$ | threshold voltage | 0.78 V |
| $R_{0\ max}$ | slope resistance * | 7.7 mΩ |

Outlines TO-247


| Sym. | Inches min. max. | Millimeter min. max. |
|------|---------------------|-------------------------|
| A | 0.185 0.209 | 4.70 5.30 |
| A1 | 0.087 0.102 | 2.21 2.59 |
| A2 | 0.059 0.098 | 1.50 2.49 |
| D | 0.819 0.845 | 20.79 21.45 |
| E | 0.610 0.640 | 15.48 16.24 |
| E2 | 0.170 0.216 | 4.31 5.48 |
| e | 0.430 BSC | 10.92 BSC |
| L | 0.780 0.800 | 19.80 20.30 |
| L1 | - 0.177 | - 4.49 |
| Ø P | 0.140 0.144 | 3.55 3.65 |
| Q | 0.212 0.244 | 5.38 6.19 |
| S | 0.242 BSC | 6.14 BSC |
| b | 0.039 0.055 | 0.99 1.40 |
| b2 | 0.065 0.094 | 1.65 2.39 |
| b4 | 0.102 0.135 | 2.59 3.43 |
| c | 0.015 0.035 | 0.38 0.89 |
| D1 | 0.515 - | 13.07 - |
| D2 | 0.020 0.053 | 0.51 1.35 |
| E1 | 0.530 - | 13.45 - |
| Ø P1 | - 0.29 | - 7.39 |



Fast Diode

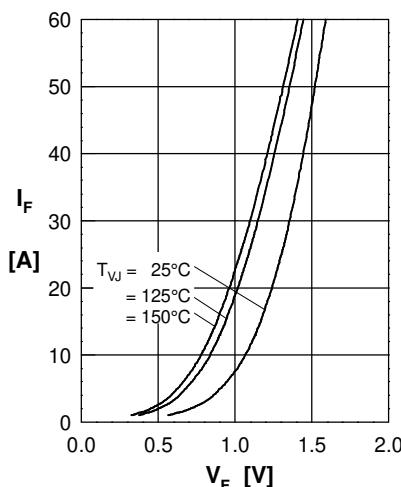


Fig. 1 Forward current versus voltage drop

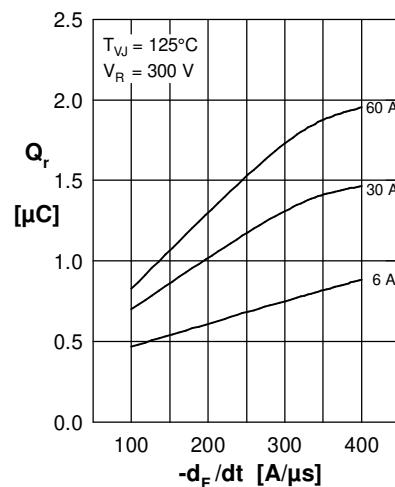


Fig. 2 Recovery charge versus $-dI_F/dt$

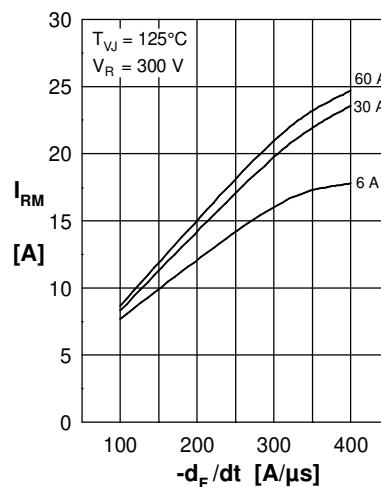


Fig. 3 Peak reverse current versus $-dI_F/dt$

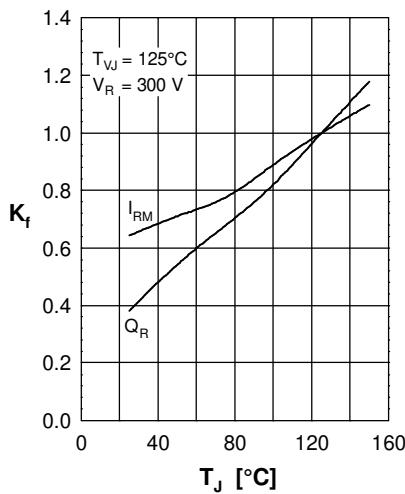


Fig. 4 Dynamic parameters vs. junction temperature

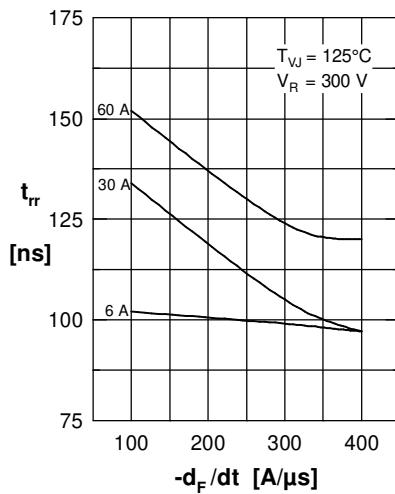


Fig. 5 Recovery time versus $-dI_F/dt$

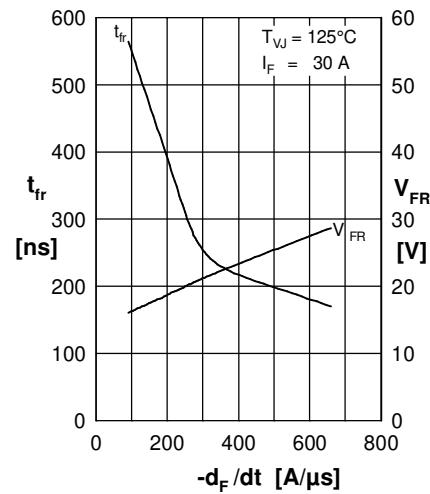


Fig. 6 Peak forward voltage versus $-dI_F/dt$

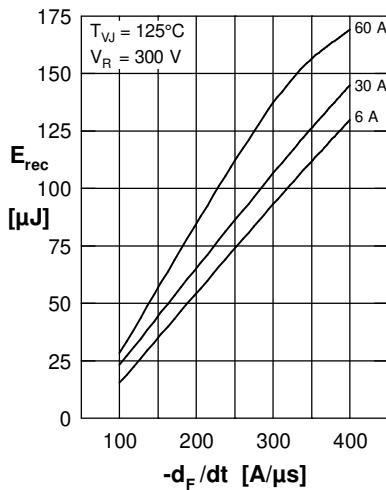


Fig. 7 Recovery energy versus $-dI_F/dt$

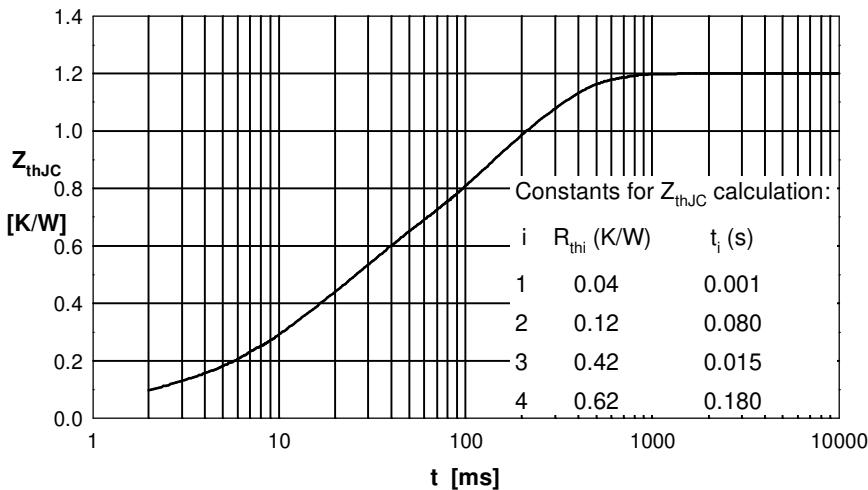


Fig. 8 Transient thermal impedance junction to case